

# BSB012N03LX3 G

### **BSB012N03LX3 G Information**

	 Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 30V 180A 2WDSON 3-WDSON For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



# **BSB012N03LX3 G Specifications**

Manufacturer Part Number	BSB012N03LX3 G
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	3-WDSON
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	39A (Ta), 180A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	169nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	16900pF @ 15V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	2.8W (Ta), 89W (Tc)
Rds On (Max) @ Id, Vgs	1.2 mOhm @ 30A, 10V
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	MG-WDSON-2, CanPAK M?
Package / Case	3-WDSON
	Report errors?

#### **BSB012N03LX3 G Guarantees**



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### **BSB012N03LX3 G Payment Methods**



#### **BSB012N03LX3 G Shipping Methods**



If you have any question about BSB012N03LX3 G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com